

Why there is a difference between optimal doping for maximal T_c and critical doping for highest ρ_s in cuprate superconductors?

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A long-standing puzzle is why there is a difference between the optimal doping $\delta_{\text{optimal}} \approx 0.15$ for the maximal superconducting (SC) transition temperature T_c and the critical doping $\delta_{\text{critical}} \approx 0.19$ for the highest superfluid density ρ_s in cuprate superconductors? This puzzle is calling for an explanation. Within the kinetic energy driven SC mechanism, it is shown that except the quasiparticle coherence, ρ_s is dominated by the *bare* pair gap, while T_c is set by the *effective* pair gap. By calculation of the ratio of the *effective* and the *bare* pair gaps, it is shown that the coupling strength decreases with increasing doping. This doping dependence of the coupling strength induces a shift from the critical doping for the maximal value of the *bare* pair gap parameter to the optimal doping for the maximal value of the *effective* pair gap parameter, which leads to a difference between the optimal doping for the maximal T_c and the critical doping for the highest ρ_s .

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The parent compounds of cuprate superconductors are Mott insulators with an antiferromagnetic long-range order (AFLRO)². However, this AFLRO is suppressed by doped charge carriers, then superconductivity arises from the binding of charge carriers into Cooper pairs³, thereby forming a superfluid with a superconducting (SC) energy gap $\Delta(\mathbf{k})$ in the single-particle excitation spectrum. This energy gap is corresponding to the energy for breaking a Cooper pair of the charge carriers and creating two excited states³, while the superfluid density ρ_s is proportional to the squared amplitude of the macroscopic wave function⁴, and therefore describes the SC charge carriers. In this case, both $\Delta(\mathbf{k})$ and ρ_s are thus two fundamental parameters whose variation as a function of doping and temperature provides important information crucial to understanding the details of the SC state³⁻⁵.

After intensive investigations over more than two decades, some essential features of the evolution of the SC state in cuprate superconductors with doping have been experimentally established⁵⁻¹¹: where the measured energy gap parameter $\bar{\Delta}$ and the SC transition temperature T_c show a dome-like shape doping dependence, i.e., the maximal $\bar{\Delta}$ and T_c occur around the *optimal doping* $\delta_{\text{optimal}} \approx 0.15$, and then decrease in both the underdoped and the overdoped regimes⁶⁻⁸. Moreover, the experimental measurements⁹⁻¹¹ throughout the SC dome show that the superfluid density ρ_s appears from the starting point of the SC dome, and then increases with increasing doping in the lower doped regime. However, this ρ_s reaches its highest value around the *critical doping* $\delta_{\text{critical}} \approx 0.19$, and then decreases at the higher doped regime, eventually disappearing together with $\bar{\Delta}$ at the end of the SC dome. In particular, it has been shown⁵⁻¹¹ that the maximal T_c around the *optimal doping* and the peak of ρ_s around the *critical doping* is a common feature of cuprate superconductors. Since $\bar{\Delta}$ measures the strength of the binding of charge carriers into Cooper pairs³, while ρ_s is a measure of the phase stiffness⁵, therefore $\bar{\Delta}$ and ρ_s separately describe the different aspects of the same SC charge carriers. In this case, a long-standing

puzzle is why there is a difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s ?

In this paper, we try to answer this question. Experimentally, the measured energy gap $\bar{\Delta}(\mathbf{k})$ is an *effective* energy gap⁶⁻⁸, which incorporates both the coupling strength and the *bare* energy gap $\Delta(\mathbf{k})$. Theoretically, the kinetic energy driven SC mechanism has been developed¹², where T_c is controlled by both the *effective* charge carrier pair gap and the quasiparticle coherence. Within this kinetic energy driven SC mechanism, we calculate the doping dependence of the coupling strength V_{eff} , and the result shows that V_{eff} smoothly decreases upon increasing doping from a strong-coupling case in the underdoped regime to a weak-coupling side in the overdoped regime. Our results also show that the maximal value of the *bare* charge carrier pair gap parameter appears around the *critical doping* $\delta_{\text{critical}} \approx 0.195$, then as a natural consequence, the highest ρ_s occurs around this same *critical doping*. However, the special doping dependence of V_{eff} shifts this *critical doping* for the maximal value of the *bare* charge carrier pair gap parameter to the *optimal doping* $\delta_{\text{optimal}} \approx 0.15$ for the maximal value of the *effective* charge carrier pair gap parameter, which leads to that T_c exhibits a maximum around the *optimal doping*.

Cuprate superconductors have a layered structure consisting of the two-dimensional CuO_2 planes separated by insulating layers². The single common feature is the presence of the CuO_2 plane, and it seems evident that the unusual behaviors of cuprate superconductors are dominated by this CuO_2 plane². In this case, it has been argued that the essential physics of the doped CuO_2 plane is properly accounted by the *t-J* model on a square lattice¹³. However, for discussions of the difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s , the *t-J* model can be

extended by including the exponential Peierls factors as,

$$H = -t \sum_{l\hat{\eta}\sigma} P_{l\hat{\eta}} C_{l\sigma}^\dagger C_{l+\hat{\eta}\sigma} + t' \sum_{l\hat{\eta}'\sigma} P_{l\hat{\eta}'} C_{l\sigma}^\dagger C_{l+\hat{\eta}'\sigma} + \mu \sum_{l\sigma} C_{l\sigma}^\dagger C_{l\sigma} + J \sum_{l\hat{\eta}} \mathbf{S}_l \cdot \mathbf{S}_{l+\hat{\eta}}, \quad (1)$$

supplemented by an important on-site local constraint $\sum_{\sigma} C_{l\sigma}^\dagger C_{l\sigma} \leq 1$ to remove the double occupancy, where the summation is over all sites l , and for each l , over its nearest-neighbors (NN) $\hat{\eta}$ or the next nearest-neighbors (NNN) $\hat{\eta}'$. $C_{l\sigma}^\dagger$ and $C_{l\sigma}$ are electron operators that respectively create and annihilate electrons with spin σ , $\mathbf{S}_l = (S_l^x, S_l^y, S_l^z)$ are spin operators, and μ is the chemical potential. The exponential Peierls factors $P_{l\hat{\eta}} = e^{-i(e/\hbar)\mathbf{A}(l)\cdot\hat{\eta}}$ and $P_{l\hat{\eta}'} = e^{-i(e/\hbar)\mathbf{A}(l)\cdot\hat{\eta}'}$ account for the coupling of electrons to an external magnetic field in terms of the vector potential $\mathbf{A}(l)$ ¹⁴. To incorporate the electron single occupancy local constraint in the t - J model (1), the charge-spin separation (CSS) fermion-spin theory^{15,16} has been proposed, where a spin-up annihilation (spin-down annihilation) operator for the physical electron is given by a composite operator as $C_{l\uparrow} = h_{l\uparrow}^\dagger S_l^-$ ($C_{l\downarrow} = h_{l\downarrow}^\dagger S_l^+$), with the spinful fermion operator $h_{l\sigma} = e^{-i\Phi_{l\sigma}} h_l$ that describes the charge degree of freedom of the electron together with some effects of spin configuration rearrangements due to the presence of the doped hole itself (charge carrier), while the spin operator S_i represents the spin degree of freedom of the electron, then the electron single occupancy local constraint is satisfied in analytical calculations. In this CSS fermion-spin representation, the t - J model (1) can be rewritten as,

$$H = t \sum_{l\hat{\eta}} P_{l\hat{\eta}} (h_{l+\hat{\eta}\uparrow}^\dagger h_{l\uparrow} S_l^+ S_{l+\hat{\eta}}^- + h_{l+\hat{\eta}\downarrow}^\dagger h_{l\downarrow} S_l^- S_{l+\hat{\eta}}^+) - t' \sum_{l\hat{\eta}'} P_{l\hat{\eta}'} (h_{l+\hat{\eta}'\uparrow}^\dagger h_{l\uparrow} S_l^+ S_{l+\hat{\eta}'}^- + h_{l+\hat{\eta}'\downarrow}^\dagger h_{l\downarrow} S_l^- S_{l+\hat{\eta}'}^+) - \mu \sum_{l\sigma} h_{l\sigma}^\dagger h_{l\sigma} + J_{\text{eff}} \sum_{l\hat{\eta}} \mathbf{S}_l \cdot \mathbf{S}_{l+\hat{\eta}}, \quad (2)$$

where $J_{\text{eff}} = (1 - \delta)^2 J$, and $\delta = \langle h_{l\sigma}^\dagger h_{l\sigma} \rangle = \langle h_l^\dagger h_l \rangle$ is the doping concentration.

Since the experimental measurements¹⁷ have shown that in the real space the gap function and the pairing force have a range of one lattice spacing, the *bare* energy gap parameter can be expressed as¹² $\Delta = \langle C_{l\uparrow}^\dagger C_{l+\hat{\eta}\downarrow}^\dagger - C_{l\downarrow}^\dagger C_{l+\hat{\eta}\uparrow}^\dagger \rangle = \langle h_{l\uparrow} h_{l+\hat{\eta}\downarrow} S_l^+ S_{l+\hat{\eta}}^- - h_{l\downarrow} h_{l+\hat{\eta}\uparrow} S_l^- S_{l+\hat{\eta}}^+ \rangle$. In the doped regime without AFLRO, the spin correlation functions $\langle S_l^+ S_{l+\hat{\eta}}^- \rangle = \langle S_l^- S_{l+\hat{\eta}}^+ \rangle = \chi_1$, and then the *bare* energy gap parameter can be rewritten as $\Delta = -\chi_1 \Delta_h$, with the *bare* charge carrier pair gap parameter $\Delta_h = \langle h_{l+\hat{\eta}\downarrow} h_{l\uparrow} - h_{l+\hat{\eta}\uparrow} h_{l\downarrow} \rangle$, which shows that the *bare* energy gap is closely related to the *bare* charge carrier pair gap, therefore the essential physics in the SC state is dominated by the corresponding one in the charge carrier pairing state. For a microscopic description of the SC state

in cuprate superconductors, the kinetic energy driven SC mechanism has been developed¹² based on the t - J model (2), where the charge carrier interaction directly from the kinetic energy by exchanging spin excitations induces a d-wave charge carrier pairing state, and then their condensation reveals the SC ground-state. Moreover, this SC state is controlled by both the *effective* energy gap and the quasiparticle coherence. Within this kinetic energy driven SC mechanism, the full charge carrier Green's function in the zero magnetic field case has been obtained explicitly in the Nambu representation as^{16,18},

$$\mathbb{G}(\mathbf{k}, i\omega_n) = Z_{\text{hF}} \frac{i\omega_n \tau_0 + \bar{\xi}_{\mathbf{k}} \tau_3 - \bar{\Delta}_{\text{hZ}}(\mathbf{k}) \tau_1}{(i\omega_n)^2 - E_{\text{hk}}^2}, \quad (3)$$

where τ_0 is the unit matrix, τ_1 and τ_3 are Pauli matrices, the renormalized charge carrier excitation spectrum $\bar{\xi}_{\mathbf{k}} = Z_{\text{hF}} \xi_{\mathbf{k}}$, with the mean-field charge carrier excitation spectrum $\xi_{\mathbf{k}} = Z t \chi_1 \gamma_{\mathbf{k}} - Z t' \chi_2 \gamma'_{\mathbf{k}} - \mu$, the spin correlation function $\chi_2 = \langle S_l^+ S_{l+\hat{\eta}'}^- \rangle$, $\gamma_{\mathbf{k}} = (1/Z) \sum_{\hat{\eta}} e^{i\mathbf{k}\cdot\hat{\eta}}$, $\gamma'_{\mathbf{k}} = (1/Z) \sum_{\hat{\eta}'} e^{i\mathbf{k}\cdot\hat{\eta}'}$, Z is the number of NN or NNN sites, the renormalized charge carrier d-wave pair gap $\bar{\Delta}_{\text{hZ}}(\mathbf{k}) = Z_{\text{hF}} \bar{\Delta}_{\text{h}}(\mathbf{k})$, and the charge carrier quasiparticle spectrum $E_{\text{hk}} = \sqrt{\bar{\xi}_{\mathbf{k}}^2 + |\bar{\Delta}_{\text{hZ}}(\mathbf{k})|^2}$, where the *effective* charge carrier d-wave pair gap $\bar{\Delta}_{\text{h}}(\mathbf{k}) = \bar{\Delta}_{\text{h}}(\cos k_x - \cos k_y)/2$, and is closely related to the self-energy $\Sigma_2^{(\text{h})}(\mathbf{k}, \omega)$ in the particle-particle channel as $\bar{\Delta}_{\text{h}}(\mathbf{k}) = \Sigma_2^{(\text{h})}(\mathbf{k}, \omega)|_{\omega=0}$, while the quasiparticle coherent weight Z_{hF} is directly associated with the self-energy $\Sigma_1^{(\text{h})}(\mathbf{k}, \omega)$ in the particle-hole channel as $Z_{\text{hF}}^{-1} = 1 - \text{Re} \Sigma_{10}^{(\text{h})}(\mathbf{k}, \omega = 0)|_{\mathbf{k}=[\pi, 0]}$, with $\Sigma_{10}^{(\text{h})}(\mathbf{k}, \omega)$ is the antisymmetric part of $\Sigma_1^{(\text{h})}(\mathbf{k}, \omega)$, where the self-energies $\Sigma_1^{(\text{h})}(\mathbf{k}, \omega)$ and $\Sigma_2^{(\text{h})}(\mathbf{k}, \omega)$ have been given in Refs. 16 and 18. In this case, the *effective* charge carrier pair gap parameter $\bar{\Delta}_{\text{h}}$, Z_{hF} , and all the other order parameters have been determined by the self-consistent calculation^{16,18}. For a convenience in the following discussions, the self-consistently calculated result¹⁸ of Δ_{h} versus doping for temperature $T = 0.002J$ with parameters $t/J = 2.5$ and $t'/t = 0.3$ is replotted in Fig. 1, where the maximal $\bar{\Delta}_{\text{h}}$ occurs around the *optimal doping* $\delta_{\text{optimal}} \approx 0.15$, and then decreases in both the underdoped and the overdoped regimes.

With the help of the Green's function (3), the *bare* charge carrier pair gap parameter Δ_{h} can be evaluated explicitly as,

$$\Delta_{\text{h}} = \frac{1}{2N} \sum_{\mathbf{k}} [\cos k_x - \cos k_y]^2 \frac{Z_{\text{hF}} \bar{\Delta}_{\text{hZ}}}{E_{\text{hk}}} \tanh\left[\frac{1}{2} \beta E_{\text{hk}}\right]. \quad (4)$$

Since the pairing force and this Δ_{h} have been incorporated into the *effective* charge carrier pair gap parameter $\bar{\Delta}_{\text{h}}$ ¹², the strength V_{eff} of the attractive interaction mediated by spin excitations in the kinetic energy driven SC mechanism can therefore be obtained in terms of the ratio of $\bar{\Delta}_{\text{h}}$ and Δ_{h} as,

$$V_{\text{eff}} = \frac{\bar{\Delta}_{\text{h}}}{\Delta_{\text{h}}}. \quad (5)$$

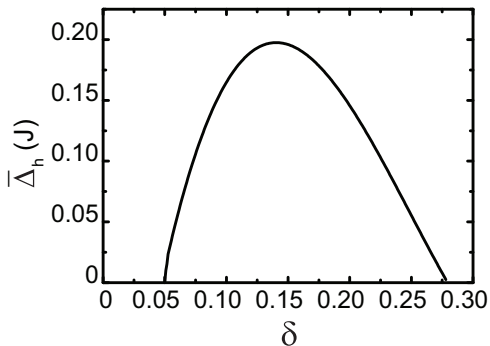


FIG. 1: The effective charge carrier pair gap parameter as a function of doping for temperature $T = 0.002J$ with parameters $t/J = 2.5$ and $t'/t = 0.3$.

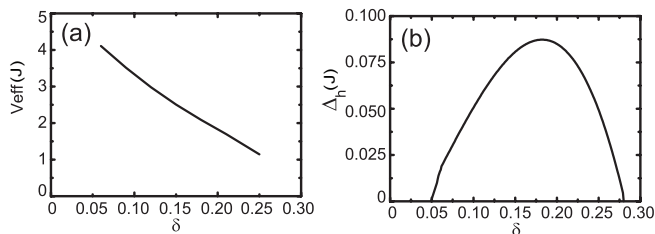


FIG. 2: (a) The coupling strength and (b) the bare charge carrier pair gap parameter as a function of doping for temperature $T = 0.002J$ with parameters $t/J = 2.5$ and $t'/t = 0.3$.

Although both $\bar{\Delta}_h$ and Δ_h measure the strength of the binding of charge carriers into charge carrier pairs, $\bar{\Delta}_h$ is an experimentally measurable quantity, while Δ_h is not. In this case, we have calculated the doping dependence of V_{eff} and Δ_h , and the results of (a) V_{eff} and (b) Δ_h as a function of doping for $T = 0.002J$ with $t/J = 2.5$ and $t'/t = 0.3$ are plotted in Fig. 2, where the coupling strength V_{eff} smoothly decreases upon increasing doping from a strong-coupling case in the underdoped regime to a weak-coupling side in the overdoped regime, which is consistent with the experimental result of cuprate superconductors¹⁹. However, Δ_h increases with increasing doping in the lower doped regime, and reaches a maximum around the *critical doping* $\delta_{\text{critical}} \approx 0.195$, then decreases with increasing doping in the higher doped regime. In comparison with the corresponding result of $\bar{\Delta}_h$ in Fig. 1, we therefore find that the special doping dependence of the coupling strength V_{eff} in Fig. 2(a) induces an important shift from the *critical doping* for the maximal Δ_h to the *optimal doping* for the maximal $\bar{\Delta}_h$, then the doping dependence of T_c is determined by $\bar{\Delta}_h$ (then both Δ_h and V_{eff}) and the quasiparticle coherent weight Z_{hF} within the kinetic energy driven SC mechanism¹². To see this point clearly, T_c as a function of doping with $t/J = 2.5$, $t'/t = 0.3$, and $J = 1000\text{K}$ is plotted in Fig. 3 in comparison with the corresponding experimental results⁶ of cuprate superconductors. It

is shown that T_c increases with increasing doping in the underdoped regime, and exhibits a maximum around the *optimal doping*, then decreases with increasing doping in the overdoped regime, in good agreement with the experimental results of cuprate superconductors⁶⁻⁸. In particular, T_c that is set by the *effective* pair gap and the quasiparticle coherence has been observed experimentally in cuprate superconductors⁸. We believe that this property may be a common feature for all superconductors, since in spite of the electron-phonon SC mechanism, T_c in the conventional superconductors is also determined by the *effective* pair gap and the quasiparticle coherence²⁰.

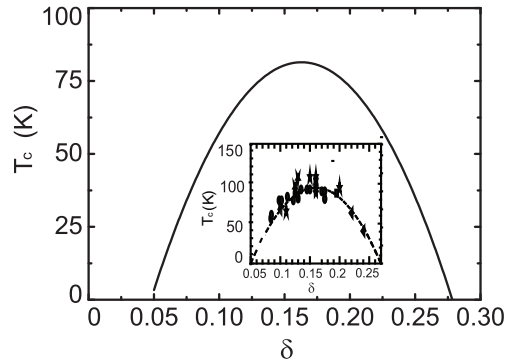


FIG. 3: The superconducting transition temperature as a function of doping with parameters $t/J = 2.5$, $t'/t = 0.3$, and $J = 1000\text{K}$. Inset: the corresponding experimental results of cuprate superconductors taken from Ref. 6.

The essential physics of the domelike shape doping dependence of T_c in cuprate superconductors can be attributed to a competition between the kinetic energy (δt) and magnetic energy (J)¹². The parent compounds of cuprate superconductors are the Mott insulators², when charge carriers are doped into a Mott insulator, there is a gain in the kinetic energy per charge carrier proportional to t due to hopping, however, at the same time, the magnetic energy is decreased, costing an energy of approximately J per site. As a consequence, the strength of the spin excitation spectrum decreases with increasing doping, which leads to a decrease of the coupling strength V_{eff} with increasing doping in the framework of the kinetic energy driven SC mechanism. Moreover, in the underdoped regime, the coupling strength V_{eff} in Fig. 2(a) is very strong, this implies that the most doped charge carriers can be bound into the charge carrier pairs, then the number of the charge carrier pairs and T_c increase with increasing doping. However, in the overdoped regime, the coupling strength V_{eff} is relatively weak. In this case, not all doped charge carriers can be bound to form the charge carrier pairs by this weakly attractive interaction, and therefore the number of the charge carrier pairs and T_c decrease with increasing doping. In particular, the *optimal doping* is a balance point, where the number of the charge carrier pairs and the coupling strength V_{eff} are optimally matched. This is why the T_c in cuprate superconductors exhibits a domelike shape doping dependence.

Now we turn to discuss the doping dependence of the superfluid density. The external magnetic field $\mathbf{B} = \text{rot}\mathbf{A}$ applied to the system usually represents a large perturbation, but the induced field generated by supercurrents cancels the external field over most of the volume of the sample. As a consequence, the net field acts only very near the surface on a scale of the magnetic field penetration depth, and then it can be treated as a weak perturbation on the system as a whole. In this case, the Meissner effect can be successfully studied within the linear response approach²¹, where the response current density J_μ and the vector potential A_ν are related by a nonlocal kernel of the response function $K_{\mu\nu}$ as,

$$J_\mu(\mathbf{q}, \omega) = - \sum_{\nu=1,2,3} K_{\mu\nu}(\mathbf{q}, \omega) A_\nu(\mathbf{q}, \omega). \quad (6)$$

This kernel of the response function in Eq. (6) can be separated into two parts as $K_{\mu\nu}(\mathbf{q}, \omega) = K_{\mu\nu}^{(d)}(\mathbf{q}, \omega) + K_{\mu\nu}^{(p)}(\mathbf{q}, \omega)$, where $K_{\mu\nu}^{(d)}$ and $K_{\mu\nu}^{(p)}$ are the corresponding diamagnetic and paramagnetic parts, respectively, and are closely related to the current-current correlation function. The vector potential $\mathbf{A}$ has been coupled to electrons, which are now represented by $C_{l\uparrow} = h_{l\uparrow}^\dagger S_l^-$ and $C_{l\downarrow} = h_{l\downarrow}^\dagger S_l^+$ in the CSS fermion-spin representation. In this case, the electron polarization operator is expressed as $\mathbf{P} = -e \sum_{i\sigma} \mathbf{R}_i C_{i\sigma}^\dagger C_{i\sigma} = e \sum_{i\sigma} \mathbf{R}_i h_i^\dagger h_i$, and then the current operator $\mathbf{j}$ in the presence of the vector potential A_ν is obtained by evaluating the time-derivative of this polarization operator. According to this current operator $\mathbf{j}$, the diamagnetic and paramagnetic parts of the response kernel have been obtained in the static limit as²²,

$$K_{\mu\nu}^{(d)}(\mathbf{q}, 0) = -\frac{4e^2}{\hbar^2} (\chi_1 \phi_1 t - 2\chi_2 \phi_2 t') \delta_{\mu\nu} = \frac{1}{\lambda_L^2} \delta_{\mu\nu}, \quad (7a)$$

$$K_{\mu\nu}^{(p)}(\mathbf{q}, 0) = \frac{1}{N} \sum_{\mathbf{k}} \gamma_\mu(\mathbf{k} + \mathbf{q}, \mathbf{k}) \gamma_\nu^*(\mathbf{k} + \mathbf{q}, \mathbf{k}) [L_1(\mathbf{k}, \mathbf{q}) + L_2(\mathbf{k}, \mathbf{q})] = K_{\mu\nu}^{(p)}(\mathbf{q}, 0) \delta_{\mu\nu}, \quad (7b)$$

where the charge carrier particle-hole parameters $\phi_1 = \langle h_{i\sigma}^\dagger h_{i+\hat{q}\sigma} \rangle$ and $\phi_2 = \langle h_{i\sigma}^\dagger h_{i+\hat{q}'\sigma} \rangle$, $\lambda_L^{-2} = -4e^2(\chi_1 \phi_1 t - 2\chi_2 \phi_2 t')/\hbar^2$, while the functions $L_1(\mathbf{k}, \mathbf{q}, \omega)$ and $L_2(\mathbf{k}, \mathbf{q}, \omega)$ have been given in Ref.²². In particular, we²² have shown that in the long wavelength limit, i.e., $|\mathbf{q}| \rightarrow 0$, $K_{yy}^{(p)}(\mathbf{q} \rightarrow 0, 0) = 0$ at $T = 0$, reflecting that the long wavelength electromagnetic response is determined by the diamagnetic part of the kernel only. However, at $T = T_c$, $K_{yy}^{(p)}(\mathbf{q} \rightarrow 0, 0) = -(1/\lambda_L^2)$, which exactly cancels the diamagnetic part of the response kernel (7a), and then the Meissner effect is obtained for all $T \leq T_c$. With the help of the response kernel in Eq. (7), the magnetic field penetration depth $\lambda(T)$ by taking into account the two-dimensional geometry of cuprate superconductors within the specular reflection model has been

evaluated as²²,

$$\lambda(T) = \frac{1}{B} \int_0^\infty h_z(x) dx = \frac{2}{\pi} \int_0^\infty \frac{dq_x}{\mu_0 K_{yy}(\mathbf{q}_x, 0, 0) + q_x^2}, \quad (8)$$

then the superfluid density $\rho_s(T)$ is obtained as $\rho_s(T) \equiv \lambda^{-2}(T)$.

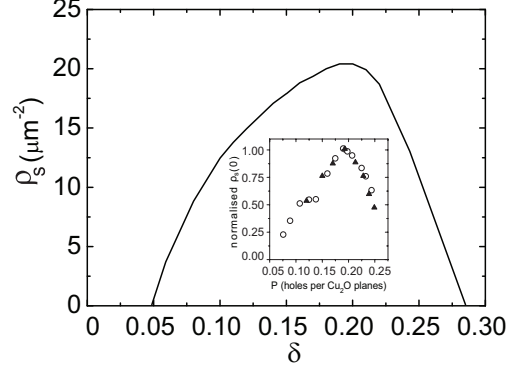


FIG. 4: The superfluid density as a function of doping for temperature $T = 0.002J$ with parameters $t/J = 2.5$, $t'/t = 0.3$, and $J = 1000\text{K}$. Inset: the corresponding experimental results of cuprate superconductors taken from Ref. 10.

In this case, for the discussions of the difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s , the result of ρ_s as a function of doping at $T = 0.002J$ with $t/J = 2.5$, $t'/t = 0.3$, and $J = 1000\text{K}$ is replotted in Fig. 4 in comparison with the corresponding experimental data¹⁰ of cuprate superconductors (inset). The result in Fig. 4 shows clearly that ρ_s increases with increasing doping in the lower doped regime, and reaches a maximum around the *critical doping* $\delta_{\text{critical}} \approx 0.195$, then decreases in the higher doped regime, in good agreement with the experimental results of cuprate superconductors⁹⁻¹¹. In particular, this anticipated value of the *critical doping* $\delta_{\text{critical}} \approx 0.195$ is very close to the *critical doping* $\delta_{\text{critical}} \approx 0.19$ obtained experimentally for different families of cuprate superconductors⁹⁻¹¹.

However, this *critical doping* $\delta_{\text{critical}} \approx 0.195$ for the highest ρ_s is different from that for T_c in Fig. 3, where the maximal T_c appears around the *optimal doping* $\delta_{\text{optimal}} \approx 0.15$. This difference can be understood within the present theoretical framework. Since ρ_s is related to the current-current correlation function, the *bare* charge carrier pair gap parameter Δ_h , the coupling strength V_{eff} , and all the other order parameters are relevant, i.e., the variation of ρ_s with doping and temperature is coupled to the doping and temperature dependence of Δ_h , V_{eff} , and all the other order parameters²². In particular, the doping-derivative of ρ_s at the *critical doping* $\delta_{\text{critical}} \approx 0.195$ is obtained as $(d\rho_s/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$. Since $\rho_s \equiv \lambda^{-2}$, $(d\rho_s/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$ is equivalent to

$(d\lambda/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$. In this case, $(d\lambda/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$ can be expressed in terms of Eq. (8) as,

$$\left[\frac{d\lambda}{d\delta}\right]_{\delta=\delta_{\text{critical}}} = -\frac{2\mu_0}{\pi} \int_0^\infty dq_x \left[\frac{1}{[\mu_0 K_{yy}(q_x, 0, 0) + q_x^2]^2} \times \frac{dK_{yy}(q_x, 0, 0)}{d\delta} \right]_{\delta=\delta_{\text{critical}}} = 0, \quad (9)$$

then it is straightforward to obtain from Eq. (7) that when $(d\rho_s/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$, $(d\Delta_h/d\delta)|_{\delta=\delta_{\text{critical}}} = 0$, which shows that the doping effects from the coupling strength V_{eff} and all the other order parameters upon ρ_s are canceled each other, then both the maximal Δ_h and the highest ρ_s appear at the same *critical doping*. Moreover, both ρ_s and Δ_h are the *bare* quantities and separately describe the different aspects of the same SC charge carriers. In this case, the domelike shape of the doping dependence of ρ_s with the highest value appeared around the *critical doping* is a natural consequence of the domelike shape of the doping dependence of Δ_h with the maximal value appeared around the same *critical doping* within the kinetic energy driven SC mechanism. In other words, except the quasiparticle coherence, ρ_s is dominated by the *bare* charge carrier pair gap parameter Δ_h , while T_c is set by the *effective* charge carrier pair gap parameter $\tilde{\Delta}_h$, this is why there is a difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s in cuprate superconductors. Finally, we have noted that ρ_s dominated by the *bare* energy gap pa-

rameter in cuprate superconductors has been observed from the photoemission experiments²³. Since in the SC state, the photoemission peak intensity as a function of doping scales with ρ_s , then a measurement of the coherent component in the quasiparticle excitation has been suggested as an indirect measure of the *bare* energy gap parameter in cuprate superconductors²³.

In conclusion, within the framework of the kinetic energy driven SC mechanism, we have discussed the origin of the difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s in cuprate superconductors. By calculation of the ratio of the *effective* and *bare* charge carrier pair gap parameters, we have shown that the coupling strength decreases with increasing doping. This special doping dependence of the coupling strength induces an important shift from the *critical doping* $\delta_{\text{critical}} \approx 0.195$ for the maximal value of the *bare* charge carrier pair gap parameter to the *optimal doping* $\delta_{\text{optimal}} \approx 0.15$ for the maximal value of the *effective* charge carrier pair gap parameter, which leads to a difference between the *optimal doping* for the maximal T_c and the *critical doping* for the highest ρ_s in cuprate superconductors.

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